CMOS Digital Integrated Circuits Silicon Monolithic

# 74HC240D,74HC244D

## 1. Functional Description

Octal Bus Buffer
 74HC240D: INVERTED, 3-STATE OUTPUTS
 74HC244D: NON-INVERTED, 3-STATE OUTPUTS

#### 2. General

 $The~74HC240D~and~74HC244D~are~high~speed~CMOS~OCTAL~BUS~BUFFERs~fabricated~with~silicon~gate~C^2MOS~technology.$ 

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The 74HC240D is an inverting 3-state buffer and the 74HC244D are non-inverting 3-state buffers having two active-low output enables.

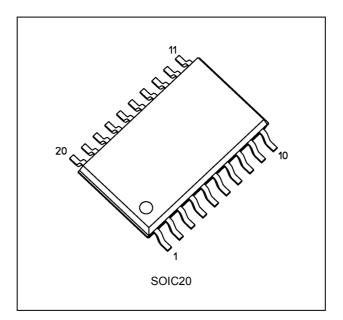
These devices are designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### 3. Features

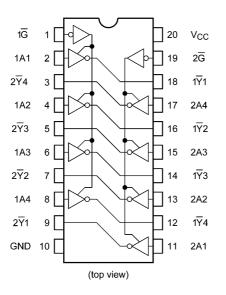
- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 1)
- (2) High speed:  $t_{pd} = 10$  ns (typ.) at  $V_{CC} = 6.0$  V
- (3) Low power dissipation:  $I_{CC} = 4.0 \ \mu A \ (max)$  at  $T_a = 25 \ ^{\circ}C$
- (4) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (5) Wide operating voltage range:  $V_{CC(opr)} = 2.0 \text{ V to } 6.0 \text{ V}$
- Note1 1:Operating Range spec of  $T_{opr} = -40$  °C to 125 °C is applicable only for the products which manufactured after July 2020.

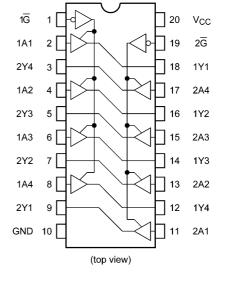
#### 4. Packaging



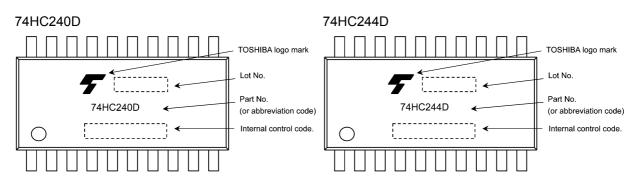
## 5. Pin Assignment

#### 74HC240D



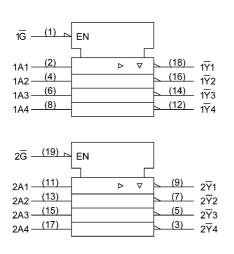


## 6. Marking



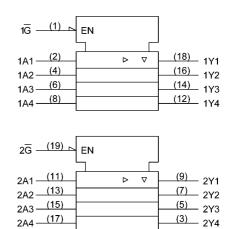
7. IEC Logic Symbol

74HC240D



#### 74HC244D

74HC244D



#### 8. Truth Table

Input G	Input An	Output Yn	Output Yn		
L	L	L	Н		
L	Н	Н	L		
Н	Х	Z	Z		

X: Don't care

Z: High impedance

Yn: 74HC244D

Yn: 74HC240D

#### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol Note		Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		±20	mA
Output diode current	I <sub>ОК</sub>		±20	mA
Output current	I <sub>OUT</sub>		±35	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	PD	(Note 1)	500	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P<sub>D</sub> derates linearly with -8 mW/°C above 85 °C

#### 10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>			2.0 to 6.0	V
Input voltage	V <sub>IN</sub>			0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>			0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		(Note 1)	-40 to 125	°C
Input rise and fall times	t <sub>r</sub> ,t <sub>f</sub>	V <sub>CC</sub> = 2.0 V		0 to 1000	ns
		V <sub>CC</sub> = 4.5 V		0 to 500	
		V <sub>CC</sub> = 6.0 V		0 to 400	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

## **11. Electrical Characteristics**

## 11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		2.0	1.50	_	_	V
				4.5	3.15	_	_	]
				6.0	4.20	—	—	
Low-level input voltage	VIL	—		2.0		—	0.50	V
				4.5		—	1.35	
				6.0		—	1.80	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -20 μA	2.0	1.9	2.0	_	V
				4.5	4.4	4.5	—	
				6.0	5.9	6.0	—	
			I <sub>OH</sub> = -6 mA	4.5	4.18	4.31	—	
			I <sub>OH</sub> = -7.8 mA	6.0	5.68	5.80	—	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 20 μA	2.0		0.0	0.1	V
				4.5		0.0	0.1	
				6.0		0.0	0.1	
			I <sub>OL</sub> = 6 mA	4.5		0.17	0.26	
			I <sub>OL</sub> = 7.8 mA	6.0		0.18	0.26	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		6.0	_	_	±0.5	μA
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	_	±0.1	μA
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	_	4.0	μA

## 11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		2.0	1.50	—	V
				4.5	3.15	_	
				6.0	4.20	—	
Low-level input voltage	VIL	—		2.0		0.50	V
				4.5		1.35	
				6.0		1.80	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -20 μA	2.0	1.9	—	<ul> <li></li> </ul>
				4.5	4.4	—	
				6.0	5.9	—	
			I <sub>OH</sub> = -6 mA	4.5	4.13	_	]
			I <sub>OH</sub> = -7.8 mA	6.0	5.63	—	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 20 μA	2.0		0.1	<ul> <li></li> </ul>
				4.5		0.1	
				6.0		0.1	
			I <sub>OL</sub> = 6 mA	4.5		0.33	
			I <sub>OL</sub> = 7.8 mA	6.0		0.33	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		6.0	_	±5.0	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0		±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	_	40.0	μA

### 11.3. DC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condition	ı	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		2.0	1.50	—	V
				4.5	3.15	_	
				6.0	4.20	_	]
Low-level input voltage	V <sub>IL</sub>	—		2.0		0.50	V
				4.5	_	1.35	
				6.0	_	1.80	]
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	—	
			I <sub>OH</sub> = -6 mA	4.5	3.7	_	
			I <sub>OH</sub> = -7.8 mA	6.0	5.2	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2.0	_	0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I <sub>OL</sub> = 6 mA	4.5	_	0.4	
			I <sub>OL</sub> = 7.8 mA	6.0	_	0.4	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		6.0		±5.0	μΑ
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0		80.0	μA

Note: Operating Range spec of T<sub>opr</sub> = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

### 11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Output transition time		t <sub>TLH</sub> ,t <sub>THL</sub>			50	2.0	—	25	60	ns
						4.5	_	7	12	
						6.0	_	6	10	
Propagation delay time		t <sub>PLH</sub> ,t <sub>PHL</sub>			50	2.0	_	36	90	ns
						4.5	_	12	18	
						6.0	_	10	15	
					150	2.0	_	51	130	
						4.5	_	17	26	
						6.0	_	14	22	
Output enable time		t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	50	2.0	_	48	125	ns
						4.5	_	16	25	
						6.0	_	14	21	
					150	2.0	_	63	165	
						4.5	_	21	33	
						6.0	_	18	28	
Output disable time		t <sub>PLZ</sub> ,t <sub>PHZ</sub>		$R_L = 1 k\Omega$	50	2.0	_	32	125	ns
						4.5	_	15	25	
						6.0	_	14	21	
Input capacitance		C <sub>IN</sub>					_	5	10	pF
Output capacitance		C <sub>OUT</sub>		_			_	10	_	pF
Power dissipation	74HC240D	C <sub>PD</sub>	(Note 1)	_			_	31		pF
capacitance	74HC244D						_	33	_	

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$  (per bit)

## 11.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)	Min	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>	—	50	2.0	—	75	ns
				4.5	_	15	
				6.0	_	13	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	—	50	2.0	_	115	ns
				4.5		23	
				6.0	_	20	
			150	2.0	—	165	
				4.5	_	33	
				6.0	_	28	
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>	R <sub>L</sub> = 1 kΩ	50	2.0	_	155	ns
				4.5	_	31	
				6.0	_	26	
			150	2.0	_	205	
				4.5	_	41	
				6.0	_	35	
Output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	R <sub>L</sub> = 1 kΩ	50	2.0	_	155	ns
				4.5	_	31	
				6.0	_	26	
Input capacitance	C <sub>IN</sub>				_	10	pF

#### 11.6. AC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C, Input: t<sub>r</sub> = t<sub>f</sub> = 6 ns)

Characteristics	Symbol	Test Condition	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)	Min	Max	Unit		
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>	_	50	2.0	—	85	ns		
				4.5	_	17	1		
				6.0	_	15	1		
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		50	2.0	_	135	ns		
				4.5	_	27			
				6.0	_	24	1		
			150	2.0	_	190	1		
				4.5	_	38	1		
				6.0	_	32	1		
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>	R <sub>L</sub> = 1 kΩ	50	2.0	_	175	ns		
				4.5	_	35	1		
				6.0	_	30	1		
					150	2.0	_	235	1
							4.5	_	47
				6.0	_	40	1		
Output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	R <sub>L</sub> = 1 kΩ	50	2.0	_	175	ns		
				4.5	_	35	1		
				6.0	_	30	1		
Input capacitance	C <sub>IN</sub>	_			—	10	pF		

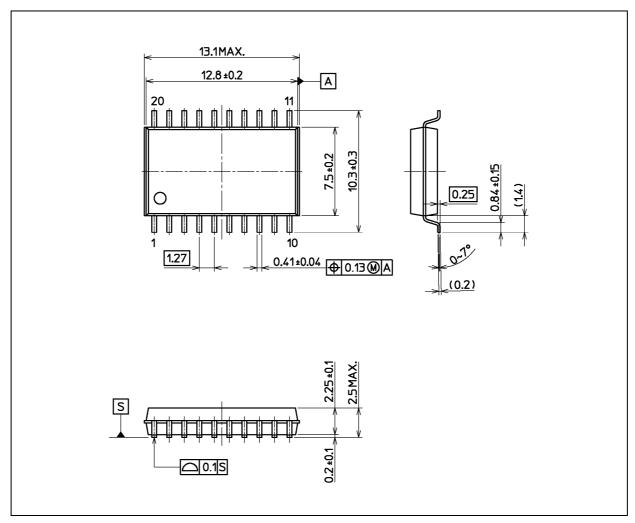
Note: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



## 74HC240D,74HC244D

#### **Package Dimensions**

Unit: mm



Weight: 0.51 g (typ.)

Package Name(s)

Nickname: SOIC20

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